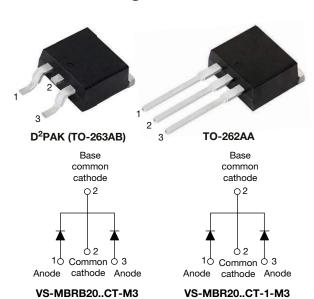
### VS-MBRB20..CT-M3, VS-MBR20..CT-1-M3

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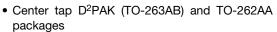
## High Performance Schottky Rectifier, 2 x 10 A



PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub> 2 x 10 A							
V <sub>R</sub>	35 V, 45 V						
V <sub>F</sub> at I <sub>F</sub>	0.72 V						
I <sub>RM</sub> max.	15 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
E <sub>AS</sub>	8 mJ						
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA						
Circuit configuration	Common cathode						

#### **FEATURES**

• 150 °C T<sub>J</sub> operation



ROHS COMPLIANT HALOGEN FREE

- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL CHARACTERISTICS VALUES UNITS										
I <sub>F(AV)</sub>	Rectangular waveform (per device)	20	- A							
I <sub>FRM</sub>	T <sub>C</sub> = 135 °C (per leg)	T <sub>C</sub> = 135 °C (per leg) 20								
V <sub>RRM</sub>		35/45	V							
I <sub>FSM</sub>	t <sub>p</sub> = 5 µs sine	1060	Α							
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V							
T <sub>J</sub>	Range	-65 to +150	°C							

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-MBRB2035CT-M3 VS-MBRB2045CT-M3 VS-MBR2045CT-1-M3 VS-MBR2045CT-1-M3								
Maximum DC reverse voltage	$V_R$	35	45	V				
Maximum working peak reverse voltage	$V_{RWM}$	33	45	V				



# VS-MBRB20..CT-M3, VS-MBR20..CT-1-M3

## Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	DL TEST CONDITIONS			UNITS		
Maximum average per leg		T 405 00 mlm IV		10			
forward current per device	I <sub>F(AV)</sub>	T <sub>C</sub> = 135 °C, rate	u v <sub>R</sub>	20	1		
Peak repetitive forward current per leg I <sub>FRM</sub> Rated V		Rated V <sub>R</sub> , square	wave, 20 kHz, T <sub>C</sub> = 135 °C	20			
Non venetiti ve nook ovvent		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1060	А		
Non-repetitive peak surge current	I <sub>FSM</sub>	Surge applied at rated load conditions halfwave, single phase, 60 Hz		150			
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 2  \text{A},  L = 4  \text{mH}$		8	mJ		
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>B</sub> typical		Frequency limited by T <sub>J</sub> maximum		2	А

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
		20 A	T <sub>J</sub> = 25 °C	0.84			
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	T <sub>.1</sub> = 125 °C	0.57	V		
		20 A	- IJ = 125 C	0.72			
Maximum instantaneous	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.1	mA		
reverse current	IRM (')	T <sub>J</sub> = 125 °C	Rated DC voltage	15			
Threshold voltage	V <sub>F(TO)</sub>	T - T mayimum		0.354	V		
Forward slope resistance	r <sub>t</sub>	ij=ijiiiaxiiiiuiii	$T_J = T_J$ maximum		mΩ		
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range	600	pF			
Typical series inductance	L <sub>S</sub>	Measured from top of term	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs		

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width  $<300~\mu s,$  duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temper	erature range	TJ		-65 to 150	°C				
Maximum storage tempe	erature range	T <sub>Stg</sub>		-65 to 175					
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	2.0	000				
Typical thermal resistance case to heatsink	e,	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W				
Annyayimata wajaht				2	g				
Approximate weight				0.07	OZ.				
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm (lbf · in)				
Mounting torque	maximum		Non-iubricated tilleads	12 (10)					
Marking device			Consisted D2DAY (TO 262AD)	MBRB2	2035CT				
			Case style D <sup>2</sup> PAK (TO-263AB)	MBRB2	2045CT				
			Consisted TO 262AA	MBR20	35CT-1				
			Case style TO-262AA	MBR20	45CT-1				



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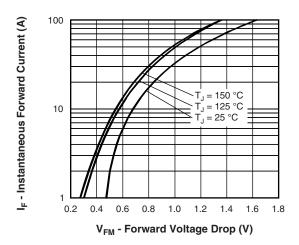


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

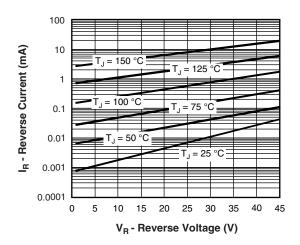


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage (Per Leg)

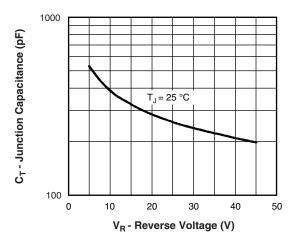


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

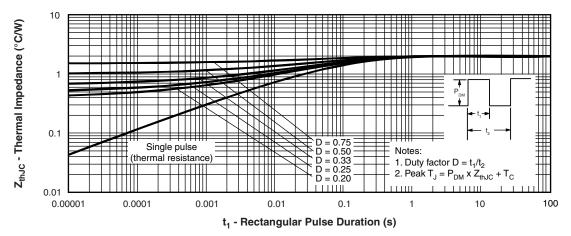


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)



Allowable Case Temperature (°C)

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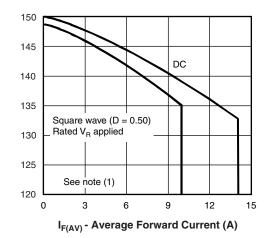


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

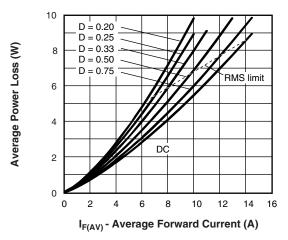


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

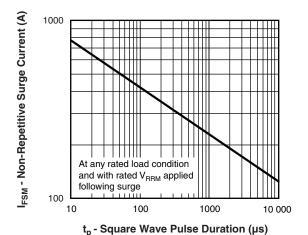


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

#### Note

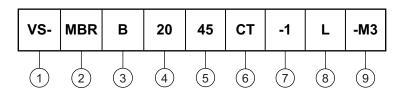
<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = rated V_R$ 

## VS-MBRB20..CT-M3, VS-MBR20..CT-1-M3

Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Essential part number

3 - • B = D<sup>2</sup>PAK (TO-263AB) 7 None • None = TO-262AA 7 = -1

• None = TO-262AA

Current rating (20 = 20 A)

- Voltage ratings

- CT = essential part number

7 - • None =  $D^2PAK (TO-263AB)$  3 = B

• -1 = TO-262AA

3 None

35 = 35 V

45 = 45 V

8 - • None = tube

• L = tape and reel (left oriented - for D<sup>2</sup>PAK (TO-263AB) only)

• R = tape and reel (right oriented - for D<sup>2</sup>PAK (TO-263AB) only)

9 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-MBRB2035CT-M3	50	Antistatic plastic tubes						
VS-MBRB2045CTL-M3	800	13" diameter plastic tape and reel						
VS-MBRB2045CT-M3	50	Antistatic plastic tubes						
VS-MBRB2045CTR-M3	800	13" diameter plastic tape and reel						
VS-MBR2035CT-1-M3	50	Antistatic plastic tubes						
VS-MBR2045CT-1-M3	50	Antistatic plastic tubes						

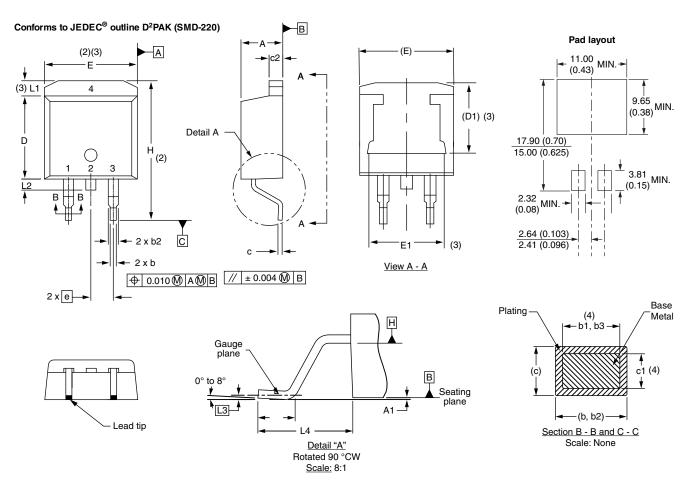
LINKS TO RELATED DOCUMENTS							
Dimensions D <sup>2</sup> PAK (TO-263AB) <u>www.vishay.com/doc?96164</u>							
Differsions —	TO-262AA	www.vishay.com/doc?96165					
De deservices information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444					
Part marking information —	TO-262AA	www.vishay.com/doc?95443					
Packaging information		www.vishay.com/doc?96424					
SPICE model		www.vishav.com/doc?95504					



### Vishay Semiconductors

### D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES SYMBOL		MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

Revision: 13-Jul-17 Document Number: 96164

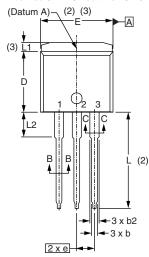


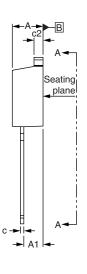
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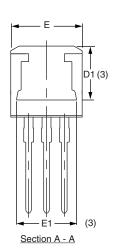
### **TO-262AA**

#### **DIMENSIONS** in millimeters and inches

#### Modified JEDEC® outline TO-262







**⊕** 0.010 **M** A**M** B

#### Lead assignments

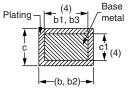


**Diodes** 

1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIN	IETERS	INC	INCHES			
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
А	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54 BSC		0.100	BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.56	3.71	0.140	0.146			

#### **Notes**

(4) Dimension b1 and c1 apply to base metal only

Controlling dimension: inches

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)



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